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- Power down high impedance inputs and outputs
- $\pm 24$  mA output drive ( $V_{CC} = 3.0V$ )
- Latch-up performance exceeds 500mA
- ESD performance:
  - Human body model > 2000V
  - Machine model > 200V

### General Description

The LCX06 contains six inverters/buffers. The inputs tolerate voltages up to 7V allowing the interface of 5V systems to 3V systems.

The outputs of the LCX06 are open drain and can be connected to other open drain outputs to implement

The 74LCX06 is fabricated with advanced CMOS technology to achieve high speed operation while maintaining CMOS low power dissipation.

### Ordering Information

| Order Number | Package Number | Package Description  |
|--------------|----------------|--|
| 74LCX06M     | M14A           | 14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow |
| 74LCX06SJ    | M14D           | 14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide                |
| 74LCX06MTC   | MTC14          | 14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide  |

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering number.

All packages are lead free per JEDEC: J-STD-020B standard.

### Connection Diagram

### Logic Symbol

IEEE/IEC

### Pin Description

## Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

| Symbol    | Parameter   | Rating          |
|-----------|---|-----------------|
| $V_{CC}$  | Supply Voltage  | -0.5V to +7.0V  |
| $V_I$     | DC Input Voltage  | -0.5V to +7.0V  |
| $V_O$     | DC Output Voltage, Output in HIGH or LOW State <sup>(1)</sup> | -0.5V to +7.0V  |
| $I_{IK}$  | DC Input Diode Current, $V_I < GND$                           | -50mA           |
| $I_{OK}$  | DC Output Diode Current                                       |                 |
|           | $V_O < GND$   | -50mA           |
|           | $V_O > V_{CC}$  | +50mA           |
| $I_O$     | DC Output Sink Current  | +50mA           |
| $I_{CC}$  | DC Supply Current per Supply Pin                              | ±100mA          |
| $I_{GND}$ | DC Ground Current per Ground Pin                              | ±100mA          |
| $T_{STG}$ | Storage Temperature   | -65°C to +150°C |

**Note:**

1.  $I_O$  Absolute Maximum Rating must be observed.

## Recommended Operating Conditions<sup>(2)</sup>

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding them or designing to absolute maximum ratings.

| Symbol   | Parameter      | Min. | Max. | Units |
|----------|----------------|------|------|-------|
| $V_{CC}$ | Supply Voltage |      |      |       |
|          | Operating      | 2.0  | 3.6  | V     |
|          | Data Retention | 1.5  | 3.6  |       |
| $V_I$    | Input Voltage  | 0    | 5.5  | V     |
| $V_O$    |                |      |      |       |

**Note:**

2. Unused inputs must be held HIGH or LOW. They may not float.

## DC Electrical Characteristics

| Symbol           | Parameter                             | V <sub>CC</sub> (V) | Conditions                               | T <sub>A</sub> = -40°C to +85°C |      | Units |
|------------------|---------------------------------------|---------------------|--|---------------------------------|------|-------|
|                  |                                       |                     |  | Min.                            | Max. |       |
| V <sub>IH</sub>  | HIGH Level Input Voltage              | 2.3–2.7             |  | 1.7                             |      | V     |
|                  |                                       | 2.7–3.6             |  | 2.0                             |      |       |
| V <sub>IL</sub>  | LOW Level Input Voltage               | 2.3–2.7             |  |                                 | 0.7  | V     |
|                  |                                       | 2.7–3.6             |  |                                 | 0.8  |       |
| V <sub>OL</sub>  | LOW Level Output Voltage              | 2.3–3.6             | I <sub>OL</sub> = 100μA                  |                                 | 0.2  | V     |
|                  |                                       | 2.3                 | I <sub>OL</sub> = 8mA                    |                                 | 0.6  |       |
|                  |                                       | 2.7                 | I <sub>OL</sub> = 12mA                   |                                 | 0.4  |       |
|                  |                                       | 3.0                 | I <sub>OL</sub> = 16mA                   |                                 | 0.4  |       |
|                  |                                       |                     | I <sub>OL</sub> = 24mA                   |                                 | 0.55 |       |
| I <sub>I</sub>   | Input Leakage Current                 | 2.3–3.6             | 0 ≤ V <sub>I</sub> ≤ 5.5V                |                                 | ±5.0 | μA    |
| I <sub>OFF</sub> | Power-Off Leakage Current             | 0                   | V <sub>I</sub> or V <sub>O</sub> = 5.5V  |                                 | 10   | μA    |
| I <sub>CC</sub>  | Quiescent Supply Current              | 2.3–3.6             | V <sub>I</sub> = V <sub>CC</sub> or GND  |                                 | 10   | μA    |
|                  |                                       |                     | 3.6V ≤ V <sub>I</sub> ≤ 5.5V             |                                 | ±10  |       |
| ΔI <sub>CC</sub> | Increase in I <sub>CC</sub> per Input | 2.3–3.6             | V <sub>IH</sub> = V <sub>CC</sub> - 0.6V |                                 | 500  | μA    |
| I <sub>OHZ</sub> | Off State Current                     | 2.0–3.6             | V <sub>O</sub> = 5.5V                    |                                 | 10   | μA    |

## AC Electrical Characteristics

| Symbol                              | Parameter              | T <sub>A</sub> = -40°C to +85°C, R <sub>L</sub> = 500Ω  |      |  |      |   |      | Units |
|-------------------------------------|------------------------|---|------|--|------|---|------|-------|
|                                     |                        | V <sub>CC</sub> = 3.3V ± 0.3V,<br>C <sub>L</sub> = 50pF |      | V <sub>CC</sub> = 2.7V,<br>C <sub>L</sub> = 50pF |      | V <sub>CC</sub> = 2.5V ± 0.2V,<br>C <sub>L</sub> = 30pF |      |       |
|                                     |                        | Min.  | Max. | Min.   | Max. | Min.  | Max. |       |
| t <sub>PZL</sub> , t <sub>PLZ</sub> | Propagation Delay Time | 0.8   | 3.7  | 1.0  | 4.1  | 0.8   | 3.5  | ns    |

## Dynamic Switching Characteristics

| Symbol           | Parameter                                   | V <sub>CC</sub> (V) | Conditions  | T <sub>A</sub> = 25°C | Unit |
|------------------|---|---------------------|---|-----------------------|------|
|                  |   |                     |   | Typical               |      |
| V <sub>OLP</sub> | Quiet Output Dynamic Peak V <sub>OL</sub>   | 3.3                 | C <sub>L</sub> = 50pF, V <sub>IH</sub> = 3.3V, V <sub>IL</sub> = 0V | 0.9                   | V    |
|                  |   | 2.5                 | C <sub>L</sub> = 30pF, V <sub>IH</sub> = 2.5V, V <sub>IL</sub> = 0V | 0.7                   |      |
| V <sub>OLV</sub> | Quiet Output Dynamic Valley V <sub>OL</sub> | 3.3                 | C <sub>L</sub> = 50pF, V <sub>IH</sub> = 3.3V, V <sub>IL</sub> = 0V | -0.8                  | V    |
|                  |   | 2.5                 | C <sub>L</sub> = 30pF, V <sub>IH</sub> = 2.5V, V <sub>IL</sub> = 0V | -0.6                  |      |

## Capacitance

| Symbol           | Parameter                     | Conditions   | Typical | Units |
|------------------|-------------------------------|--|---------|-------|
| C <sub>IN</sub>  | Input Capacitance             | V <sub>CC</sub> = Open, V <sub>I</sub> = 0V or V <sub>CC</sub>             | 7       | pF    |
| C <sub>OUT</sub> | Output Capacitance            | V <sub>CC</sub> = 3.3V, V <sub>I</sub> = 0V or V <sub>CC</sub>             | 8       | pF    |
| C <sub>PD</sub>  | Power Dissipation Capacitance | V <sub>CC</sub> = 3.3V, V <sub>I</sub> = 0V or V <sub>CC</sub> , f = 10MHz | 25      | pF    |

### AC Loading and Waveforms (Generic for LCX Family)

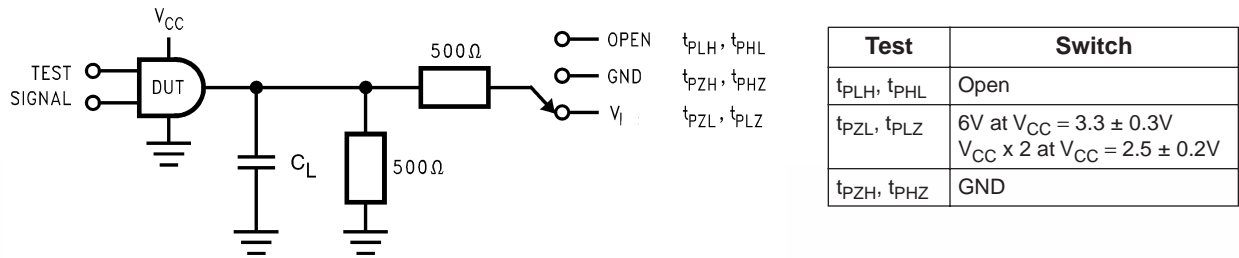
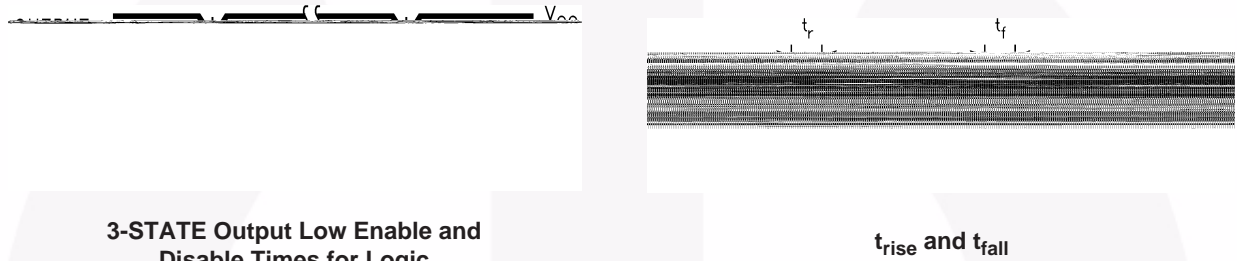


Figure 1. AC Test Circuit (C<sub>L</sub> includes probe and jig capacitance)



3-STATE Output Low Enable and Disable Times for Logic

t<sub>rise</sub> and t<sub>fall</sub>

| Symbol          | V <sub>CC</sub>        |                        |                         |
|-----------------|------------------------|------------------------|-------------------------|
|                 | 3.3V ± 0.3V            | 2.7V                   | 2.5V ± 0.2V             |
| V <sub>mi</sub> | 1.5V                   | 1.5V                   | V <sub>CC</sub> /2      |
| V <sub>mo</sub> | 1.5V                   | 1.5V                   | V <sub>CC</sub> /2      |
| V <sub>x</sub>  | V <sub>OL</sub> + 0.3V | V <sub>OL</sub> + 0.3V | V <sub>OL</sub> + 0.15V |
| V <sub>y</sub>  | V <sub>OH</sub> - 0.3V | V <sub>OH</sub> - 0.3V | V <sub>OH</sub> - 0.15V |

Figure 2. Waveforms (Input Characteristics; f = 1MHz, t<sub>r</sub> = t<sub>f</sub> = 3ns)



8.75  
8.50

0.65

6.00

4.00  
3.80

5.60

1.70

1.27

1.75 MAX

C

1.50  
1.25

0.25  
0.10

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